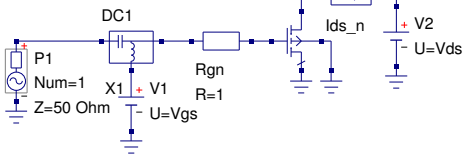


### dc simulation



EKV26pMOS1  
 L=10e-6  
 W=20e-6  
 Cox=3.45e-3  
 Vto=-0.55  
 Gamma=0.69  
 Phi=0.87  
 Kp=20e-6  
 Theta=50e-3  
 Cgso=1.5e-10  
 Cgdo=1.5e-10  
 Cgbo=4.0e-10  
 Cj0=300e-15

### Parameter sweep

SW1  
 Sim=SW2  
 Type=lin  
 Param=Vds  
 Start=0  
 Stop=-3  
 Points=31

### Parameter sweep

SW2  
 Sim=SP1  
 Type=lin  
 Param=Vgs  
 Start=2  
 Stop=-2  
 Points=201

### S parameter simulation

Equation  
 Eqn1  
 y=stoy(S)  
 Type=const  
 Values=[1 MHz]

L=10e-6  
 W=10e-6  
 Cox=3.45e-3  
 Cg=imag(y[1,1])/Omega  
 Cgpl=PlotVs( Cg/(Cox\*W\*L), Vds, Vgs)  
 Rg=PlotVs( (real(y[1,1]))/(Omega\*Omega\*Cg\*Cg), Vds, Vgs)  
 Cg\_2D=PlotVs(Cg, Vgs)  
 Omega=2\*pi\*frequency

